

NCE Automotive N-Channel Super Trench Power MOSFET

Description

The series of devices uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

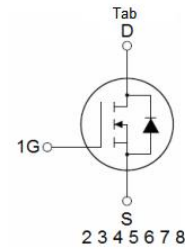
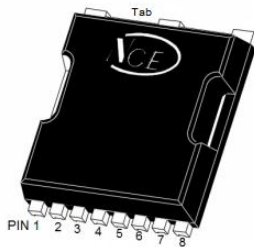
Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

General Features

- $V_{DS} = 150V, I_D = 165A$
 $R_{DS(ON)} = 5.2m\Omega$, typical@ $V_{GS} = 10V$
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔV_{ds} tested
- **AEC-Q101 qualified**

TOLL-8L



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP15T14LL	NCEAP15T14LL	TOLL-8L	-	-	-

Absolute Maximum Ratings ($T_c = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	150	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	165	A
	$I_D (T_c = 100^\circ C)$	117	A
Pulsed Drain Current	I_{DM}	660	A
Maximum Power Dissipation	P_D	375	W
Derating factor		2.5	W/ $^\circ C$
Single pulse avalanche energy (Note 1)	E_{AS}	1764	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	$^\circ C$

Thermal Characteristic

Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.4	$^\circ C/W$
Thermal Resistance, Junction-to-Ambient (Note 4)	$R_{\theta JA}$	40	$^\circ C/W$

Electrical Characteristics (T_c=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	150	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =150V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =40A	-	5.2	5.8	mΩ
Gate resistance	R _G	F=1.0MHz	-	3.3	-	Ω
Forward Transconductance	g _{FS}	V _{DS} =10V, I _D =40A	-	59	-	S
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =75V, V _{GS} =0V, F=1.0MHz	-	6100	-	pF
Output Capacitance	C _{oss}		-	700	-	PF
Reverse Transfer Capacitance	C _{rss}		-	31	-	pF
Switching Characteristics <small>(Note 2)</small>						
Turn-on Delay Time	t _{d(on)}	V _{DD} =75V, I _D =70A V _{GS} =10V, R _G =4.7Ω	-	26	-	nS
Turn-on Rise Time	t _r		-	36	-	nS
Turn-Off Delay Time	t _{d(off)}		-	47	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Q _g	V _{DS} =75V, I _D =20A, V _{GS} =10V	-	90	-	nC
Gate-Source Charge	Q _{gs}		-	30	-	nC
Gate-Drain Charge	Q _{gd}		-	22	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _F =40A	-	-	1.2	V
Diode Forward Current	I _S		-	-	165	A
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = I _S	-	146	-	nS
Reverse Recovery Charge	Q _{rr}	di/dt = 100A/μs	-	485	-	nC

Notes:

1. EAS condition : T_J=25°C, V_{DD}=50V, V_G=10V, L=0.5mH, R_G=25Ω
2. Guaranteed by design, not subject to production
3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T_{J(MAX)}=175° C. The SOA curve provides a single pulse rating.
4. The value of R_{θJA} is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25° C. The maximum allowed junction temperature of 175° C. The value in any given application depends on the user's specific board design.

Typical Electrical and Thermal Characteristics

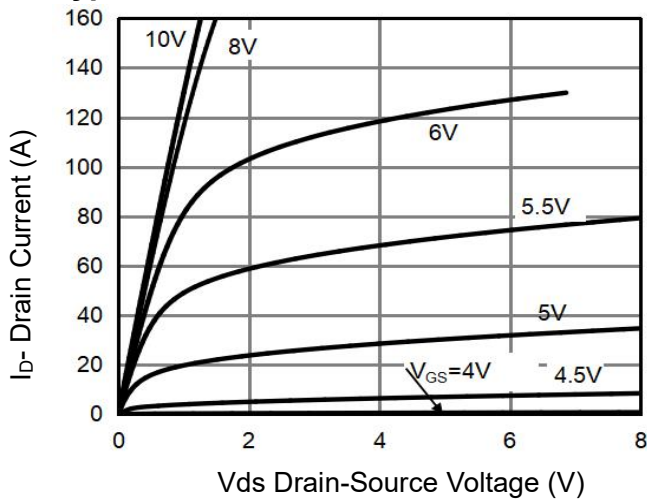


Figure 1 Output Characteristics

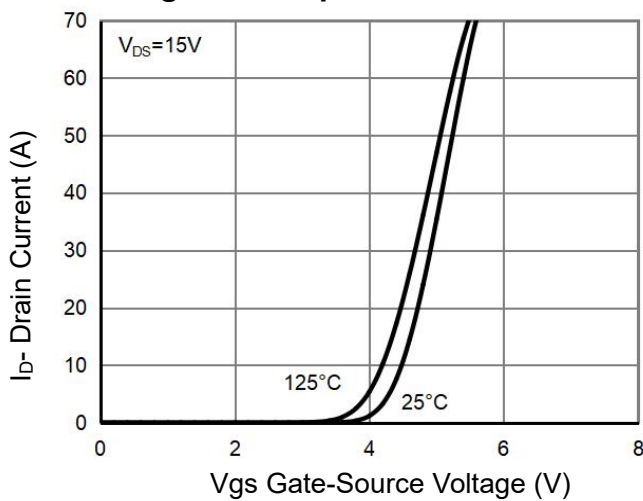


Figure 2 Transfer Characteristics

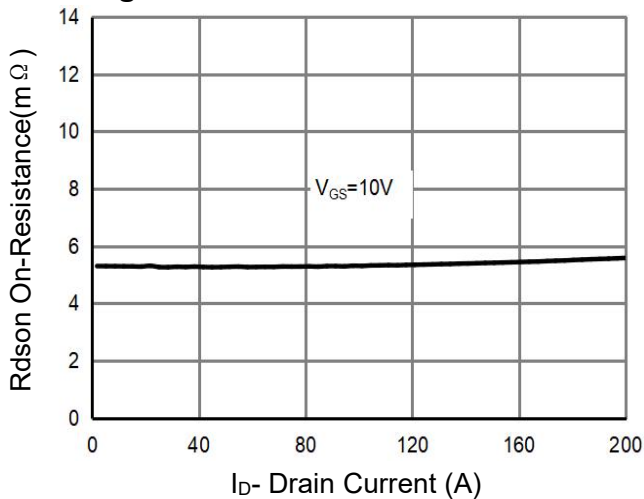


Figure 3 $R_{DS(on)}$ - Drain Current

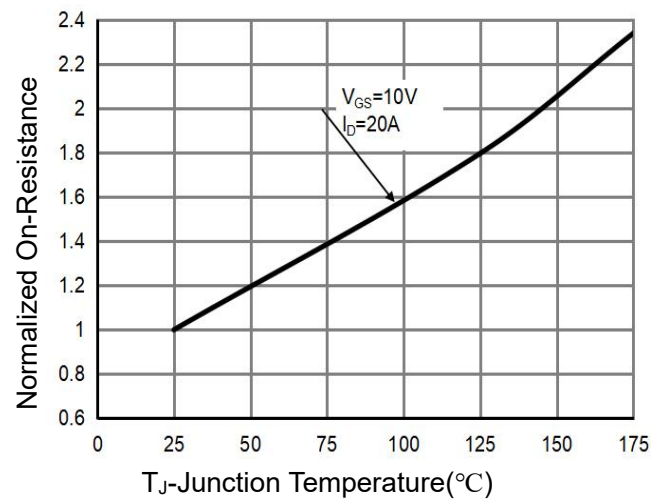


Figure 4 $R_{DS(on)}$ -Junction Temperature

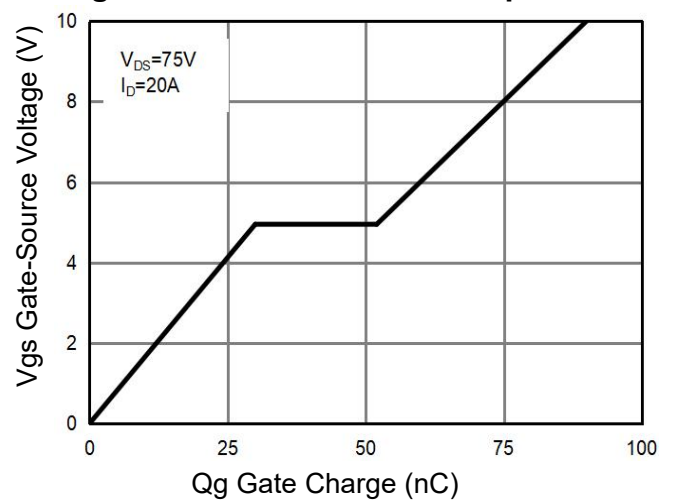


Figure 5 Gate Charge

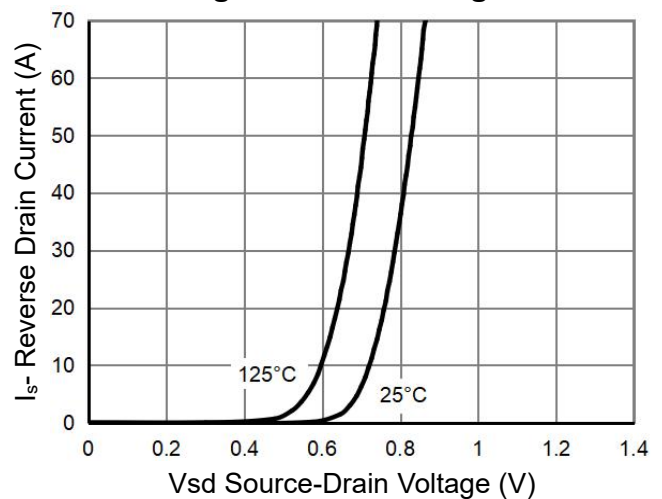


Figure 6 Source- Drain Diode Forward

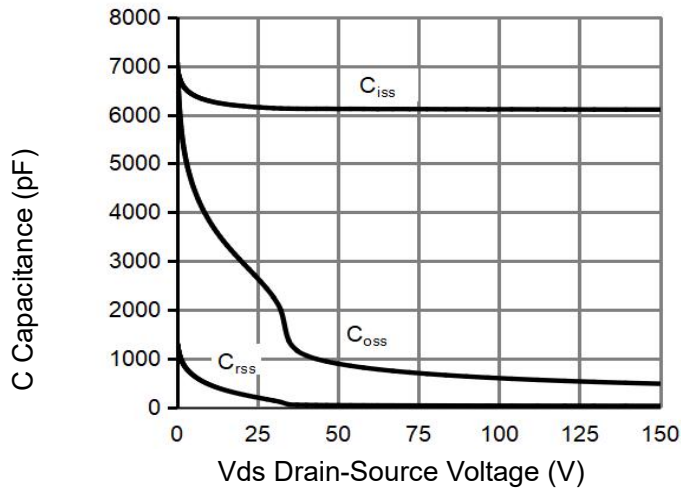


Figure 7 Capacitance vs Vds

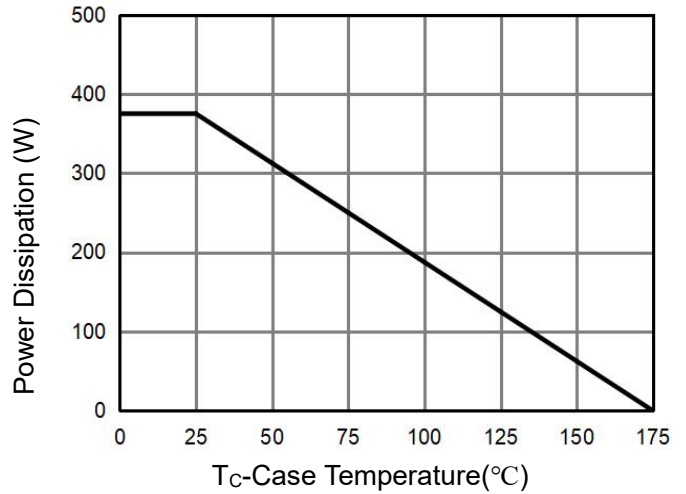


Figure 9 Power De-rating

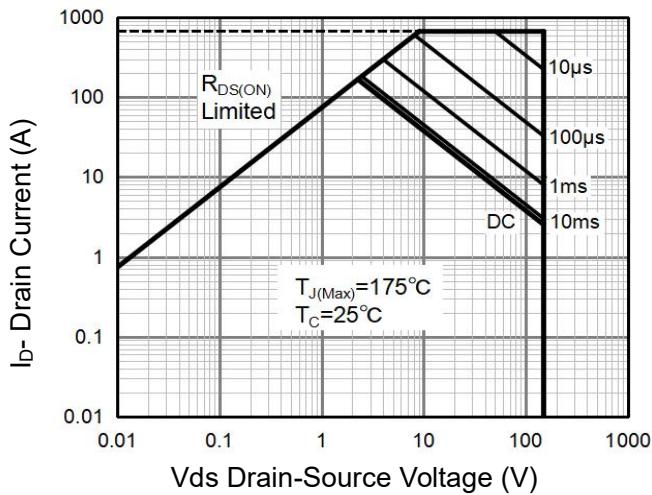


Figure 8 Safe Operation Area (Note3)

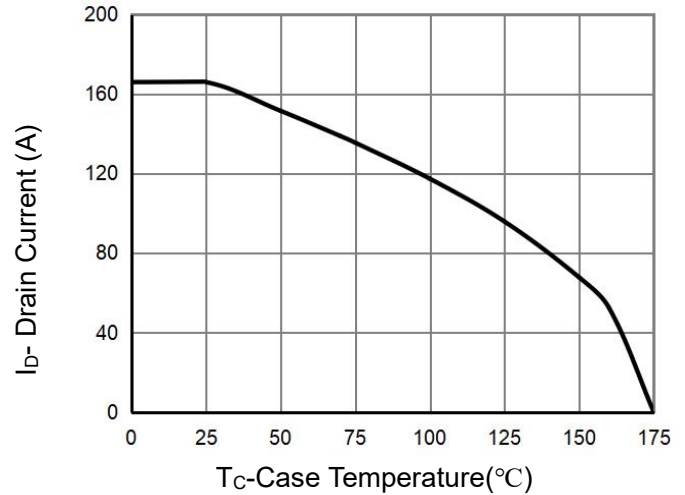


Figure 10 Current De-rating

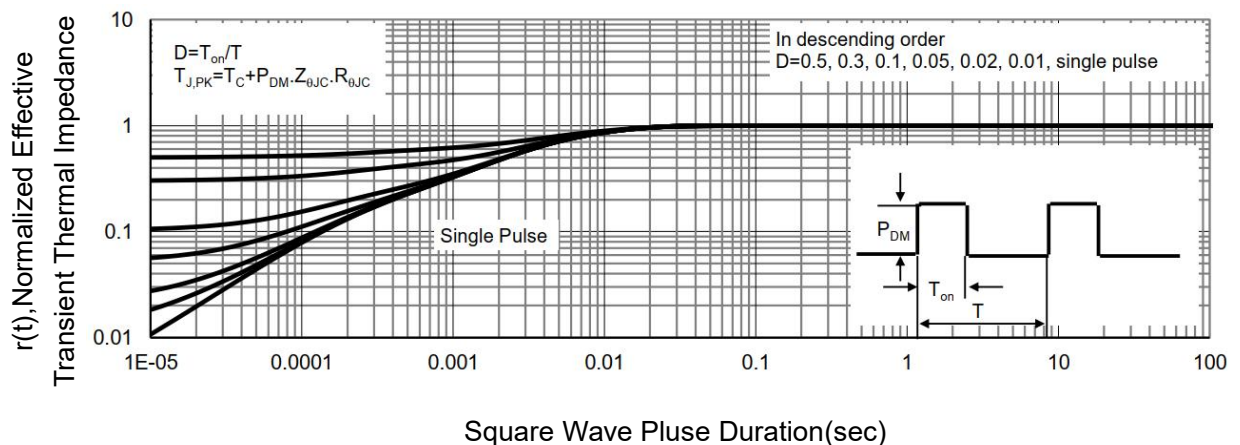
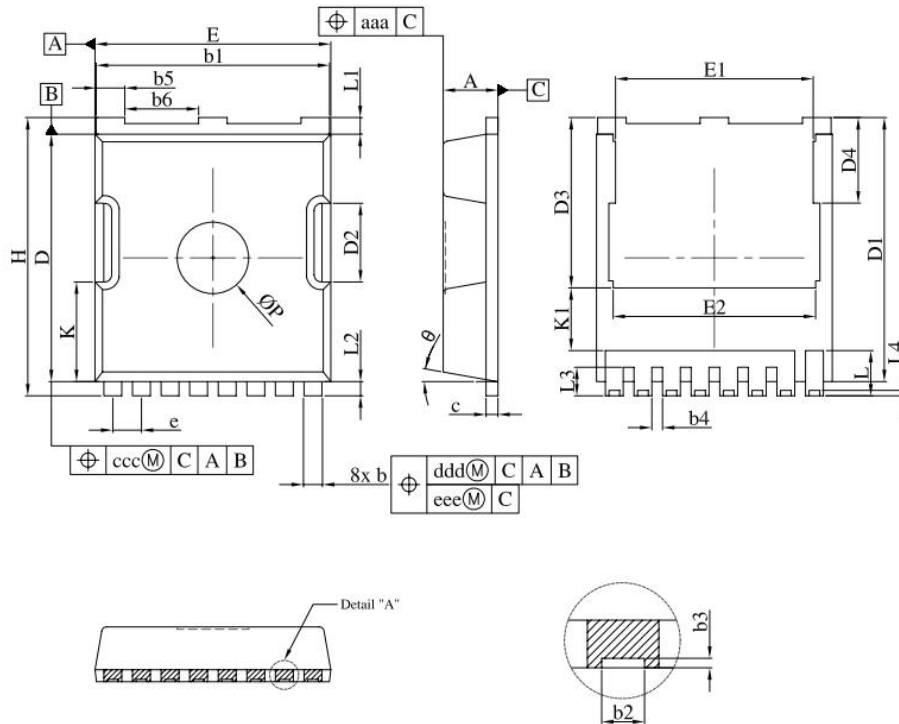


Figure 11 Normalized Maximum Transient Thermal Impedance

TOLL-8L Package Information



SYMBOL	COMMON		
	MILLIMETER		
	MIN.	NOMINAL	MAX.
A	2.20	2.30	2.40
b	0.70	0.80	0.90
b1	9.70	9.80	9.90
b2	0.36	0.45	0.55
b3	0.05	0.100	0.35
b4	0.30	0.40	0.50
b5	1.10	1.20	1.30
b6	3.00	3.10	3.20
c	0.40	0.50	0.60
D	10.28	10.38	10.55
D1	10.98	11.08	11.18
D2	3.20	3.30	3.40
D3	7.00	7.15	7.30
D4	3.44	3.59	3.74
e	1.10	1.20	1.30
E	9.80	9.90	10.00
E1	8.20	8.30	8.40
E2	8.35	8.50	8.65
H	11.50	11.68	11.85
K	4.08	4.18	4.28
K1	2.45	--	--
L	1.60	1.90	2.10
L1	0.50	0.70	0.90
L2	0.50	0.60	0.70
L3	1.00	1.20	1.30
L4	0.13	0.23	0.33
P	2.85	3.00	3.15
θ	10° REF		
aaa	0.20		
ccc	0.20		
ddd	0.25		
eee	0.20		

Revision History

Revision	Date	Subjects
V1.0	2024.12.09	Product data sheet

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